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## EBS D analysis of MgB<sub>2</sub> bulk superconductors

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**Abstract.** The grain orientation, the texture and the grain boundary misorientations are important parameters for the understanding of the magnetic properties of the bulk MgB<sub>2</sub> samples intended for super-magnet applications. Such data can be provided by electron backscatter diffraction (EBS D) analysis. However, as the grain size of the MgB<sub>2</sub> bulks is preferably in the 100-200 nm range, the common EBS D technique working in reflection operates only properly on highly dense samples. In order to achieve a reasonably good Kikuchi pattern quality on all samples, we apply here the newly developed transmission EBS D (t-EBS D) technique to several bulk MgB<sub>2</sub> samples. This method requires the preparation of TEM slices by means of focused ion-beam milling, which are then analyzed within the SEM, operating with a specific sample holder. We present several EBS D mappings of samples prepared with different techniques and at various reaction temperatures.

**Keywords:** MgB<sub>2</sub>, microstructure, EBS D

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## 1. Introduction

Applications of bulk superconductors like magnetic bearings, couplings and trapped field magnets ("super-magnets") require the fabrication of large sample sizes, as the maximum achievable trapped field depends on the sample size [1]. For this purpose, the superconducting material involved should be cheap, and to be produced in a simple, cost-effective manner.  $\text{MgB}_2$  fulfills this demand being free of rare-earth materials which are expensive, and large samples can be produced by a conventional sintering technique. Therefore,  $\text{MgB}_2$  is a good candidate for a large variety of applications [2-6]. Strong currents can flow in polycrystalline  $\text{MgB}_2$  samples due to strongly-linked grains, and the grain boundaries are strong flux pinning sites as in conventional  $\text{Nb}_3\text{Sn}$  material [7]. Of course, the parameters of the sintering process must be properly optimized in order to produce a material with high critical current density [8-10]. Therefore, a thorough microstructure characterization of  $\text{MgB}_2$  samples prepared using different techniques and at different reaction temperatures is necessary to understand the resulting superconducting properties. An important tool to achieve this goal is provided by the electron backscatter diffraction (EBSD) technique. However, up to now there are only some reports using this technique in the literature on  $\text{MgB}_2$  material [11-13], which is strongly linked to the problems arising in the sample preparation stage. Here, we present a solution to these problems by means of the newly developed transmission EBSD technique (t-EBSD) [14,15], which is based on the fabrication of TEM slices by means of focused ion-beam milling. The TEM slices are then investigated in the SEM using a special sample holder. This approach was recently carried out in the literature on nano-grained  $\text{MgB}_2$  [16] and graphene-oxide doped  $\text{MgB}_2$  samples [17].

This paper is organized as follows: In Sec. 2, the sample and sample surface preparation and the preparation of the TEM slices required for EBSD are outlined. In Sec. 3, we describe firstly the motivation for the microstructure analysis. Then, the EBSD results are presented and discussed. Finally, some conclusions are drawn.

## 2. Experimental procedure

### 2.1 Sample and surface preparation

The polycrystalline MgB<sub>2</sub> samples from SIT, Tokyo were fabricated by using a low-cost, in-situ solid state reaction. Mg and B powders of high purity were pressed into pellets and sintered under argon atmosphere at temperatures varying from 775 to 950 °C. All samples were kept at the target temperature for 3 h. More details on the preparation route and the respective x-ray data are given elsewhere [9,18].

The MgB<sub>2</sub> samples with high density (HD) were synthesized in a spark plasma sintering system in DC mode at a temperature of 1200 °C. The pulsed electric current (2000 A, 4 V) was passed through the sample under dynamic vacuum (10<sup>-3</sup> bar) while a 50 MPa uniaxial pressure was applied. This preparation procedure is described in detail in Ref. [19].

The properties of all the samples investigated here are summarized in Table 1, presenting the sample names, the reaction type, the reaction temperature, the onset temperature of the superconducting transition,  $T_c$ , the measured current density at 20 K in self-field (measured by SQUID magnetometry), the normal-state resistivity [ $\rho(41\text{ K})$ ],  $\Delta\rho = \rho(300\text{ K}) - \rho(41\text{ K})$  as a measure for the grain connectivity, the EBSD type applied, the mean grain size and the grain boundary length (as determined by EBSD). The  $T_c$  data stem from resistance measurements on the samples; for more details see Ref. [20]. The EBSD measurements are discussed in Sec. 3 below.

For the magnetic measurements, small specimens with dimensions of  $1.5 \times 1.5 \times 0.5\text{ mm}^3$  were cut from the bulk MgB<sub>2</sub> samples using a diamond saw. The magnetic data were recorded using a MPMS 7XL SQUID magnetometer from Quantum Design.

For the microstructure analysis, the sample surfaces were polished mechanically with SiO<sub>2</sub> papers, diamond paste and Struers SiO<sub>2</sub> OPS suspension to a total roughness of several nanometers. Details of the polishing procedure are described in Ref. [21]. For the EBSD analysis, the mechanically polished surfaces of the samples were further treated by low-angle argon ion-polishing (5 KeV, 5 min) to further

improve the image quality of the Kikuchi patterns as described in Ref. [22] for the investigation of ferrite samples.

The TEM slices for the t-EBSD measurements were produced by focused-ion beam (FIB) milling in a dual-beam FIB workstation (FEI) using a routine allowing for reduced surface damage. After lifting-off the TEM slice from the sample with the micromanipulator, the surface is ion-polished in a separate step by 2 KeV Ga-ions to a thickness of about 80 nm. This step serves to further reduce the preparation damage of the surface area and for a further thinning of the sample to be transparent to the electron beam. Figure 1 presents a typical TEM slice fabricated from a MgB<sub>2</sub> sample in two magnifications (inset).

## 2.2 EBSD

The EBSD analysis was performed in a JEOL 7000F SEM microscope equipped with a TSL (TexSEM Labs, UT) analysis unit. The Kikuchi patterns were generated at an acceleration voltage of 15 kV, and were recorded by means of a DigiView camera system. To produce a crystallographic orientation map, the electron beam was scanned over a selected surface area and the resulting Kikuchi patterns were indexed and analyzed automatically. This represents the common EBSD method working in reflection mode (hereafter called standard configuration). A detailed description of the measurement procedure can be found in Refs. [21,23]. Automated EBSD scans were performed with a step size down to 50 nm. The working distance in the standard configuration was set to 15 mm, while for t-EBSD a working distance of 5 mm was chosen.

Although any preparation technique for TEM samples can be used also for t-EBSD, the fabrication of TEM slices by FIB are best suited to select the proper sample area for the analysis. For t-EBSD, the TEM-slices were mounted in the SEM on a specially fabricated sample holder allowing for the correct 70° inclination of the sample required for EBSD. The stage with the sample holder is inclined to an angle of -20°, which enables together with the sample mounting the same detector position to be used for the EBSD detector as in the standard configuration. Here, the electron beam is passing through the

sample (transmission mode) and the electron cone is formed on the backside of the sample. The electron beam operates at 30 kV, and the working distance is set to 5 mm. The EBSD stepsize was 5 nm. An image of our sample holder and the entire arrangement within the SEM chamber is presented in Fig. 2.

### 2.3 Magnetic measurements

The magnetic characterization measurements were performed using SQUID magnetometry (Quantum Design MPMS). The critical current densities were calculated from the magnetization loops using the extended Bean model for rectangular samples. For SQUID measurements, small samples ( $2 \times 2 \times 1.5 \text{ mm}^3$ ) were cut from the big pellets.

## 3. Results and discussion

Firstly, we present our main motivation for the microstructure analysis. Figure 3 (a) shows the critical current density,  $j_c$ , as a function of applied field for all the MgB<sub>2</sub> samples at two selected temperatures,  $T = 10 \text{ K}$  and  $30 \text{ K}$ . All samples show an nearly exponential decay of  $j_c$  with increasing  $H$ . The sample with the highest  $j_c$  at self-field is HD1200, followed by sample Sin800 (see also Table 1). The sample Sin950 has a lower  $j_c$  at self-field, but at fields above 1 T,  $j_c$  is higher than all other samples. The inset presents the irreversibility lines,  $H_{\text{irr}}(T)$ , for all samples. The irreversibility fields,  $H_{\text{irr}}$ , are determined from the  $j_c(H)$ -data using a criterion of  $100 \text{ Acm}^{-2}$ . At low temperatures, the samples HD1200 and Sin950 have the highest  $H_{\text{irr}}$  values. When now performing a pinning force scaling analysis of all the data following the model of Dew-Hughes [24,25], we arrive at the situation shown in Fig. 3 (b). Here, we have selected only data at 10 K and 30 K for clarity; for more data see also Ref. [17]. The peak positions in the scaling are important to judge about the active flux pinning mechanism. Peak positions,  $h_0$ , are found between 0.18 and 0.4, which indicates a strong variation of the origin of flux pinning. The samples Sin775 and Sin800 reveal a non-scaling of the data as the 30 K

data yield much higher peak positions as the low-temperature data. In this case, the flux pinning mechanism clearly changes with temperature. Sample Sin950 shows a much smaller shift with temperature and the peak positions obtained indicate pinning at point pins. The sample HD1200 has the lowest peak position of all samples of  $h_0 = 0.18$  at 10 K and 0.24 at 30 K, which speaks for a dominating pinning at grain boundaries. In order to explain these differences observed in Fig. 3, the microstructure analysis was performed.

Now, we turn to the EBSD analysis of the  $\text{MgB}_2$  samples. Performing EBSD analysis on the mechanically polished surfaces of the sintered  $\text{MgB}_2$  samples lead to several problems due to the high porosity of the samples, as the density achieved is only about 50-55 % of the theoretical value. The average grain size of these samples is about 200–400 nm as observed in Refs. [9,10]. On these samples, we could only record some Kikuchi patterns which could be indexed as  $\text{MgB}_2$  phase, but no automated EBSD mapping was possible. Furthermore, the sample Sin950 also showed charging problems due to the higher resistivity [20], which is the reason why we have excluded this sample from the further analysis. All this lead us to perform t-EBSD instead of the standard EBSD in order to achieve a higher spatial resolution with reduced charging effects. In contrast to the sintered  $\text{MgB}_2$  samples, the highly dense spark-plasma sintered  $\text{MgB}_2$  sample was found to work well with the standard EBSD technique.

For the EBSD analysis, we decided to run single phase scans as the XRD data [8-10] did not show any additional peaks of pure Mg or MgO. The EBSD data are presented as spatially resolved mappings. The size of the selected area is in all cases between  $5 \times 5$  and  $9 \times 9 \mu\text{m}^2$ . The image (a) gives an inverse pole figure (IPF) map in [001]-direction using a color code, given in the stereographic triangle. The map (b) is a grain size (GS) map in gray scale (scale ranges from black to white on increasing grain size) together with the EBSD-detected boundaries (rotation angle). The map (c) presents the average grain misorientation. In this map, the edge grains are excluded from the analysis. Finally, (d) gives the inverse pole figure of the respective sample section in (0001)

orientation. Figure 4 gives the data obtained on sample Sin775, Fig 5 the data of sample Sin800, Fig. 6 the ones of sample Sin875 and finally, Fig. 7 the data of sample HD1200.

The comparison of the mappings reveal several interesting points:

(i) The grain sizes decreases between the reaction temperatures of 775 °C and 800 °C, but are increasing again upon increasing the reaction temperature irrespective of the preparation technique applied.

(ii) The orientation of the grains in all sample does not show a specific texture, but the inverse pole figures show some remarkable changes, which will be discussed in the following.

(iii) The average misorientation of the grains is the smallest for the sample Sin775, and increases upon increase of the reaction temperature.

The inverse pole figures reveal an interesting behavior: Sample Sin775 shows a maximum (red area) in the center of the triangle, whereas sample Sin800 shows three maxima at the outer edge. Finally, samples Sin875 and HD1200 have two main maxima in the outer edges of the triangle. This observation demonstrates the effect of the reaction temperature on the grain arrangement.

The EBSD-determined graphs as presented in Fig. 8 give an even better insight to the details of the resulting microstructures of the samples. Figure 8 (a) presents the area fraction as function of the EBSD-determined grain size. Here it is remarkable that the samples Sin775 and Sin875 exhibit a quite similar behavior, whereas the sample Sin800 clearly reveals a large amount of small grains in the nanometer range, and the sample HD1200 shows a more uniform distribution, but also the presence of the largest grains of all samples investigated here. The formation of the small grains at temperatures around 800 °C was investigated in detail in Ref. [10]. Another piece of information is given in Table 1 showing the mean grain size for each sample as determined by the EBSD software. Due to the presence of many small grains in the measured region, the mean grain size of sample HD1200 is comparable to that of sample Sin775, while all other samples follow the basic trend. The increase of the grain size on increasing the reaction temperature was also observed in Refs. [17,26]. To validate the EBSD results, we also investigated the grain sizes on fractured surfaces of the respective samples



as depicted in Fig. 9 (a-c). Here, it is required to image the fractured surfaces with secondary electrons (see e.g., Ref. [27]). The small grain sizes of the samples Sin775 (a) and Sin800 (b) are clearly visible in comparison to sample HD1200 (c). For the statistics, we evaluated about 30 grains of each sample. The data obtained in this way are always slightly larger as the EBSD-determined grain sizes, but confirm the trends of the EBSD data presented above.

In contrast to this behavior, the number fraction of the EBSD-determined misorientation angles [Fig. 8 (b)] for all samples are strikingly similar. The grain average neighbor misorientation [Fig. 8 (c)] is also quite similar for all samples. Finally, Fig. 8 (d) shows the EBSD-determined boundary line length as function of the misorientation. Here, the samples Sin775, Sin875 and HD1200 exhibit an equal behavior, and the sample Sin800 is at a completely different level due to the reduced grain size and hence, the increased boundary length. This is also seen in Table 1 with the total grain boundary length (here all GBs are counting having a misorientation  $> 10^\circ$ ). This length increases at low reaction temperatures, and then decreases strongly on further increasing reaction temperature. This behavior is a direct consequence of the small grains obtained at a reaction temperature of about 800 °C, and then the grains are found to grow again. Therefore, the sample Sin800 can exhibit the strongest flux pinning provided by grain boundaries. This result clearly demonstrates the advantage of sintering MgB<sub>2</sub> samples at a temperature of around 800 °C.

In order to obtain a complete picture of the properties of the MgB<sub>2</sub> samples, it is necessary to regard not only the magnetic properties, but as well the electrical resistance of the samples and the resulting grain connectivity. Furthermore, the formation of secondary phase MgB<sub>4</sub> particles at elevated reaction temperatures contributes additional flux pinning at point defects. Table 1 gives the connectivity (measured as  $\Delta\rho = \rho(300\text{ K}) - \rho(41\text{ K})$ , see Ref. [20]) for some of the samples investigated here.  $\Delta\rho$  firstly decreases on increasing the reaction temperature, and then increases again. This behavior is similar to the change in grain size as seen before. The formation of MgB<sub>4</sub> particles at reaction temperatures above 850 °C provides more flux pinning sites in samples Sin875 and Sin950 (see, e.g., Ref. [10]), but the increasing  $\Delta\rho$  reduces the current flow between the grains. In contrast to this, the

sample HD1200 profits from the achieved high density, leading to densely packed grains which also improve the connectivity considerably as manifested by the smallest resistance values. On the other hand, the best connectivity and the presence of  $\text{MgB}_4$  particles do not overcome the reduced grain boundary pinning due to the increased grain growth at the high reaction temperature.

Finally, we turn to the EBSD analysis of the samples. Performing EBSD on bulk, sintered  $\text{MgB}_2$  samples in the standard configuration (i.e., in reflection mode) turned out to be difficult as the samples exhibit grain sizes in the nanometer range. The achievable resolution (= image quality of the detected Kikuchi patterns) depends strongly on the surface quality, which here cannot be as good as in samples with large grains due to the high number of grain boundaries and pores. For such a situation, the t-EBSD technique working in transmission achieves a much better resolution as recently investigated in Ref. [28] using a comparison of experimental data with simulations. The t-EBSD technique enables the EBSD analysis of nearly all types of  $\text{MgB}_2$  samples. The sample Sin950 with its low density is too brittle to survive the preparation of a TEM slice. However, the preparation of TEM slices is a costly process, which poses a problem to a general application. For samples of interest, this is feasible especially in combination with TEM analysis. In principle, other TEM sample preparation methods are also suitable to prepare samples for t-EBSD, however, the required thinning procedure of the final sample may become difficult. The handling of the samples using a nanomanipulator and the possibility to select a given area of interest for the EBSD investigation speaks in favor of the FIB-produced TEM slices.

In case that the  $\text{MgB}_2$  samples are much closer to the theoretical density, the standard EBSD technique is found to work well yielding also high image quality values. For the present study, it was important to obtain EBSD images at various sintering temperatures, enabling an important comparison to be made. The conclusions we can draw from this analysis directly influence the optimization of the sintering temperature and the sintering time. Here we may state that an ideal  $\text{MgB}_2$  sample for most applications should have a small grain size with an increased grain boundary length

for strong flux pinning, but its density must be much closer to the theoretical value as the current samples.

#### **4. Summary**

In summary, we have shown that the transmission EBSD technique works well for sintered  $\text{MgB}_2$  samples, whereas for samples close to the theoretical density, the standard EBSD technique gives reasonable results as well. The sintered samples prepared at temperatures ranging between 775 °C and 950 °C show at low reaction temperatures a decrease of the grain size, but at reaction temperatures above 800 °C an increasing average grain size. Additionally, the connectivity between the grains becomes worse. Therefore, the flux pinning of the samples prepared at the lowest temperature is the strongest due to the grains in the 100 nm range yielding the longest grain boundary length, which is clearly seen in the EBSD analysis. The sample Sin950 shows increased flux pinning at  $\text{MgB}_4$  particles providing strong pinning at point defects, but suffers from a decreasing connectivity of the grains.

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## Figure captions

Fig. 1. TEM slice prepared from a MgB<sub>2</sub> bulk sample by means of FIB milling. The inset shows some details of the sample Sin775.

Fig. 2. Arrangement of the TEM-slice sample holder in the SEM chamber, inclined by -20 degrees which enables the same detector position to be used as for standard EBSD. The inset shows the custom-built sample holder.

Fig. 3. The critical current densities,  $j_c(H)$ , and the pinning force,  $F_p$ , scaling at  $T = 10$  K and 30 K of the MgB<sub>2</sub> samples; other temperatures were omitted for clarity. (a) presents the current densities, and the inset the irreversibility lines of all samples. The blank part of the  $j_c(H)$ -curve at 10 K of sample HD1200 is due to flux jumps. (b) gives the pinning force scaling.

Fig. 4. EBSD analysis of sample Sin775. (a) is the inverse pole figure (IPF) map in (001)-direction. The color code for the orientations is given in the stereographic triangle. (b) shows a gray-scale grain size map, with the grain boundary misorientations marked in color. The respective color code is given below the map. Map (c) gives the average grain misorientation. The color code is shown on the right side of the map. Here, the edge grains are excluded from the analysis. Finally, (d) gives the inverse pole figure in [001]-direction for the present sample section.

Fig. 5. EBSD analysis of sample Sin800. (a) is the inverse pole figure (IPF) map in (001)-direction. The color code for the orientations is given in the stereographic triangle at Fig. 4 (a). (b) shows a gray-scale grain size map, with the grain boundary misorientations marked in color. The respective color code is given below the map. Map (c) gives the average grain misorientation. The color code is

shown on the right side of the map. Here, the edge grains are excluded from the analysis. Finally, (d) gives the inverse pole figure in [001]-direction for the present sample section.

Fig. 6. EBSD analysis of sample Sin875. (a) is the inverse pole figure (IPF) map in (001)-direction. The color code for the orientations is given in the stereographic triangle at Fig. 4 (a). (b) shows a gray-scale grain size map, with the grain boundary misorientations marked in color. The respective color code is given below the map. Map (c) gives the average grain misorientation. The color code is shown on the right side of the map. Here, the edge grains are excluded from the analysis. Finally, (d) gives the inverse pole figure in [001]-direction for the present sample section.

Fig. 7. EBSD analysis of sample HD1200. (a) is the inverse pole figure (IPF) map in (001)-direction. The color code for the orientations is given in the stereographic triangle at Fig. 4 (a). (b) shows a gray-scale grain size map, with the grain boundary misorientations marked in color. The respective color code is given below the map. Map (c) gives the average grain misorientation. The color code is shown on the right side of the map. Here, the edge grains are excluded from the analysis. Finally, (d) gives the inverse pole figure in [001]-direction for the present sample section.

Fig. 8. EBSD-determined graphs of all samples under study. (a) shows the area fraction as function of the grain size, (b) gives the distribution of the misorientation angles, (c) shows the average grain neighbor misorientation and (d) the boundary line length per area as function of the misorientation.

Fig. 9. Backscatter electron images of broken surfaces of samples Sin775 (a), Sin800 (b) and HD1200 (c) for comparison with the EBSD data.



Table 1: Data of all samples under study. The  $T_{c,onset}$  and the normal-state resistivity [ $\rho(41\text{ K})$ ] are determined by resistance measurements (for details, see Ref. [20]); the critical current density at 20 K and self-field is determined by SQUID measurements.

$\Delta\rho = \rho(300\text{ K}) - \rho(41\text{ K})$  is a measure for the connectivity of the grains, see Ref. [20].

Sample	Sin775	Sin800	Sin875	Sin950	HD1200
$T_{process}$ [°C]	775	800	875	950	1200
Type	sintered	sintered	sintered	sintered	spark-plasma
$T_{c,onset}$ [K]	38.05	38.96	39.95	39.87	38.78
$j_c$ (20 K) [Acm <sup>-2</sup> ]	108.63	135.17	126.32	95.24	321.94
Normal-state resistance $\rho(41\text{ K})$ [ $\mu\Omega\text{cm}$ ]	111	57	62	66	5
$\Delta\rho$ [ $\mu\Omega\text{cm}$ ]	140	77	107	113	30
EBSD	t-EBSD	t-EBSD	t-EBSD	none	standard
mean grain size [ $\mu\text{m}$ ]	0.23	0.12	0.33	–	0.24
total GB length per area [ $\mu\text{m}^{-1}$ ]	12.18	27.66	9.68	–	7.23

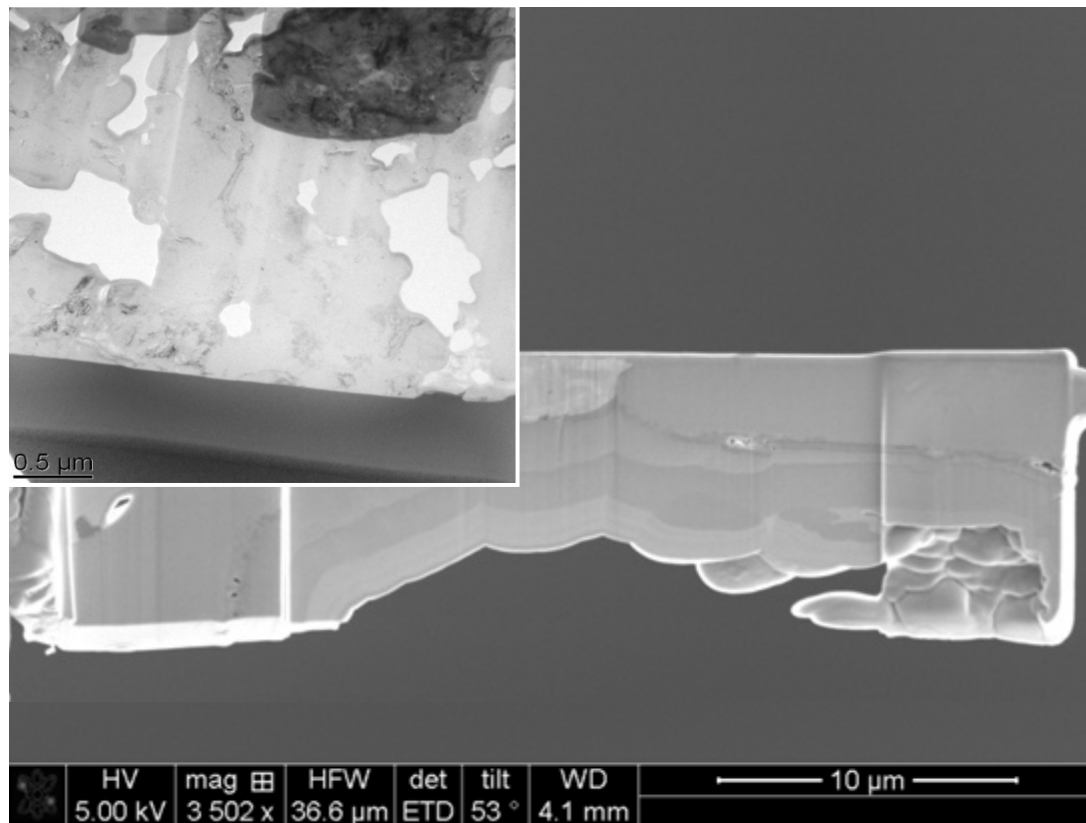


Fig. 1

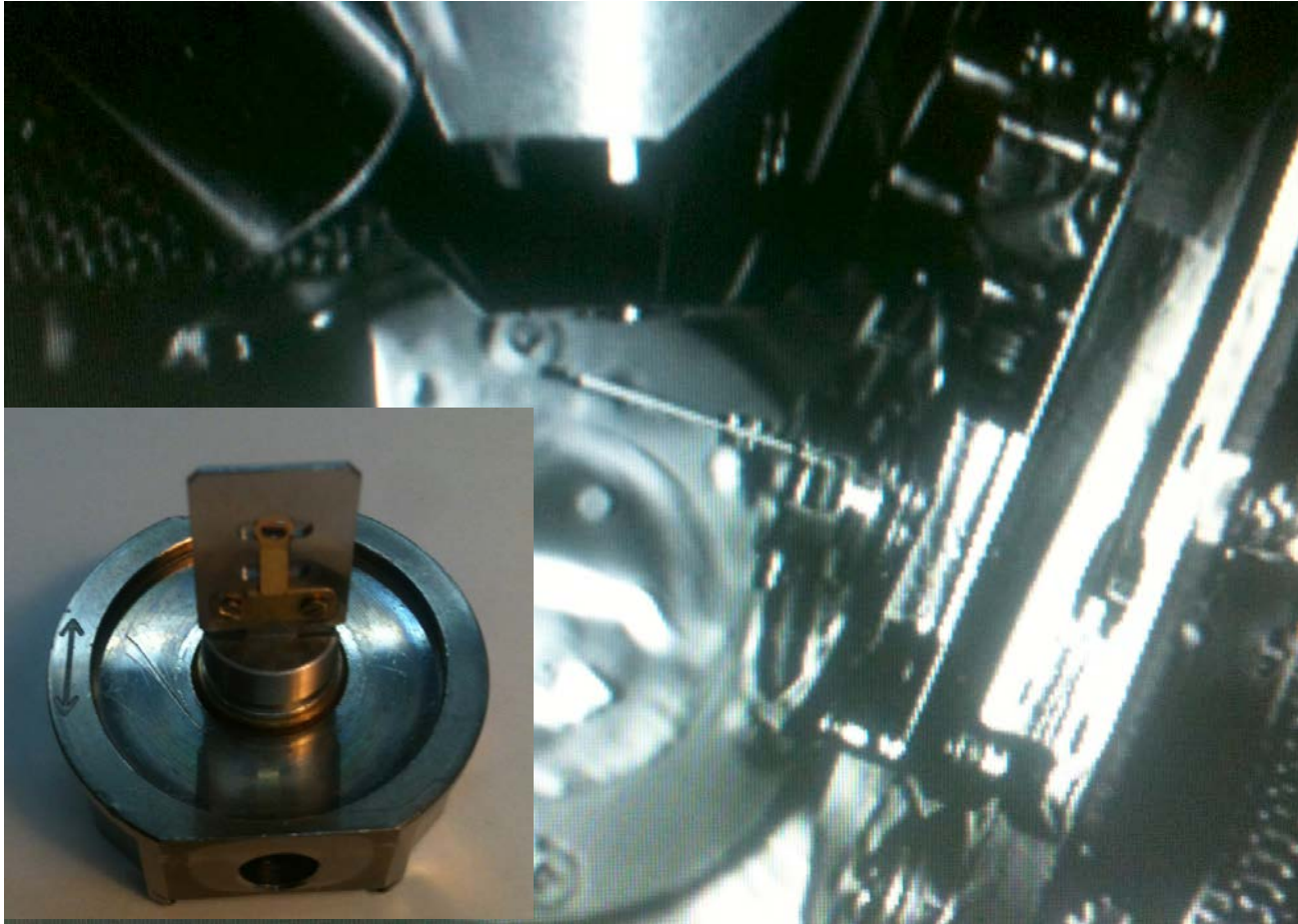


Fig. 2

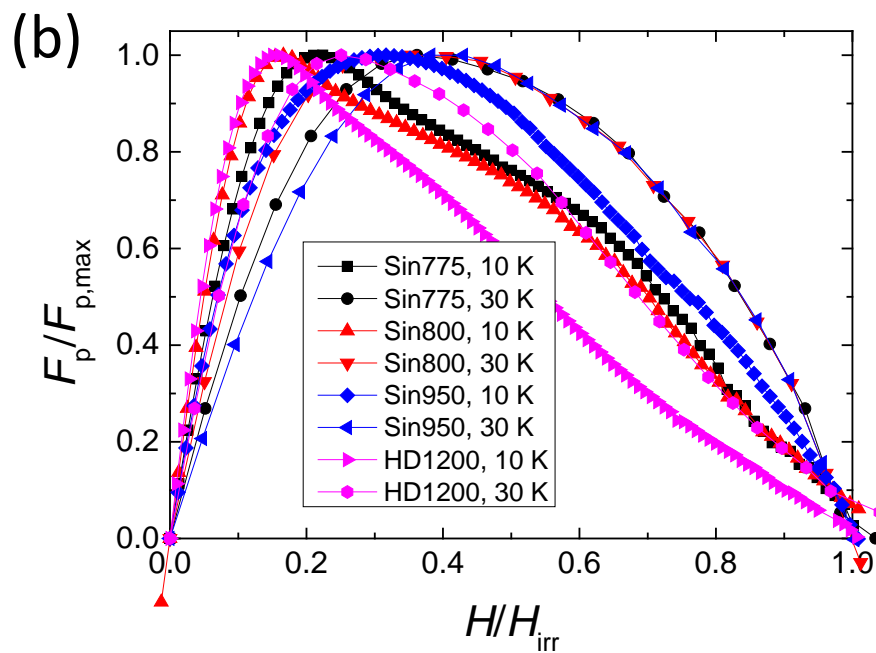
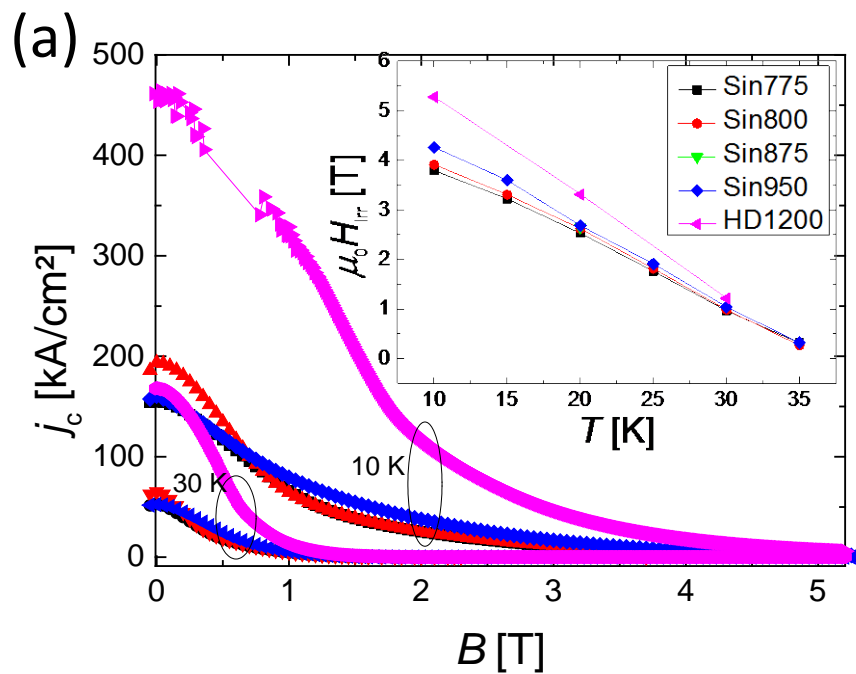
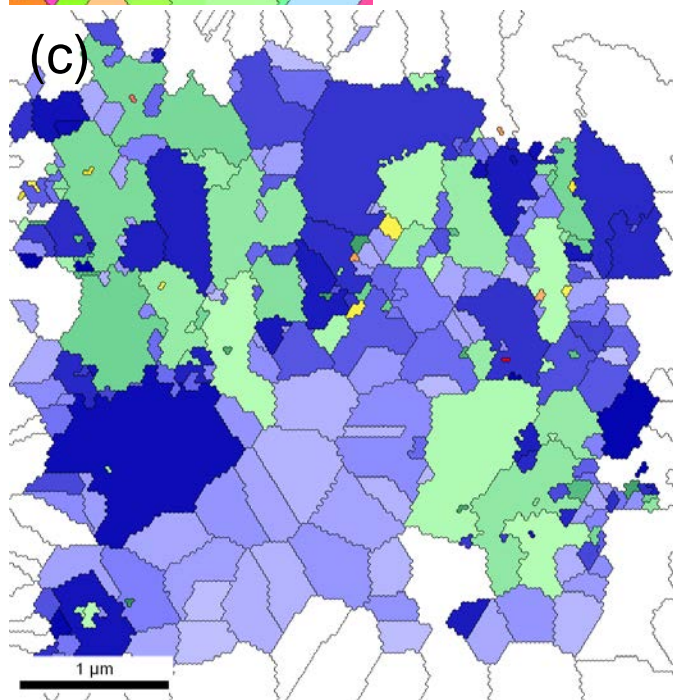
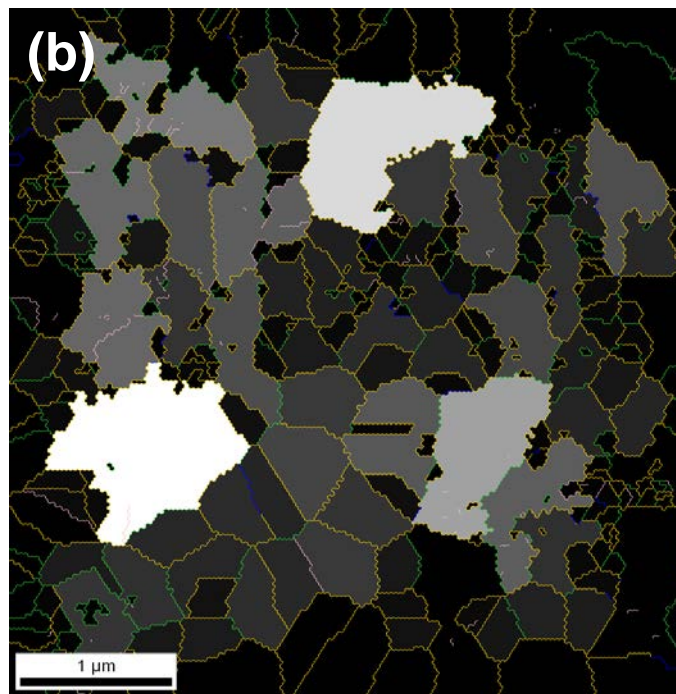
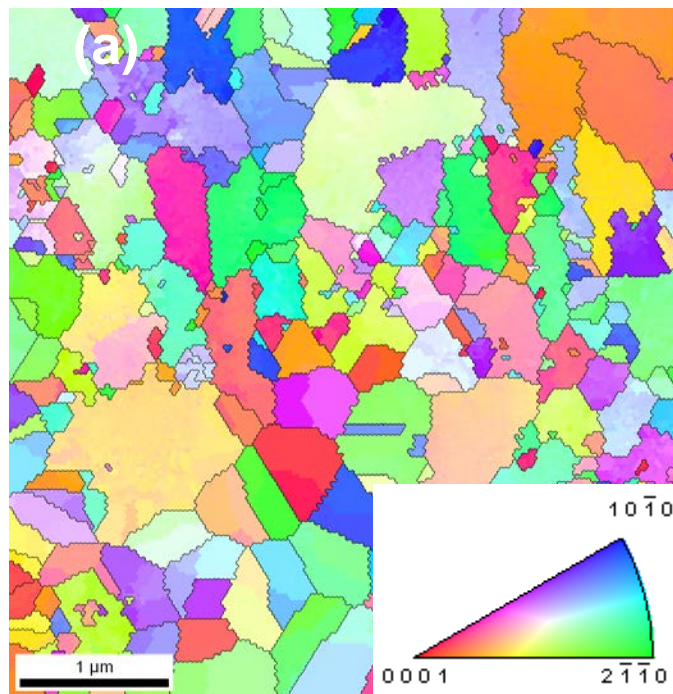











Fig. 3



-  5 – 10°
-  10 – 45°
-  45 – 90°
-  90 – 180°

[001]

-  0 – 0.62
-  0.62 – 1.15
-  1.15 – 1.75
-  1.75 – 1.95
-  1.95 – 2.44

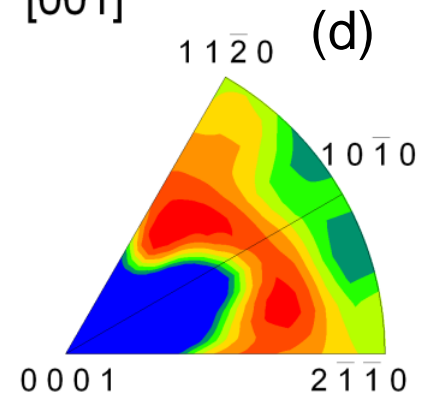


Fig. 4

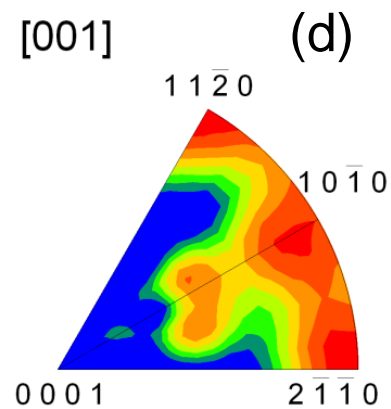
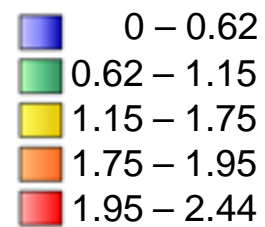
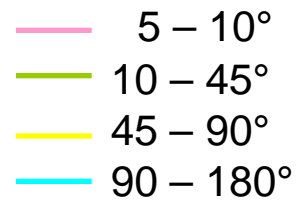
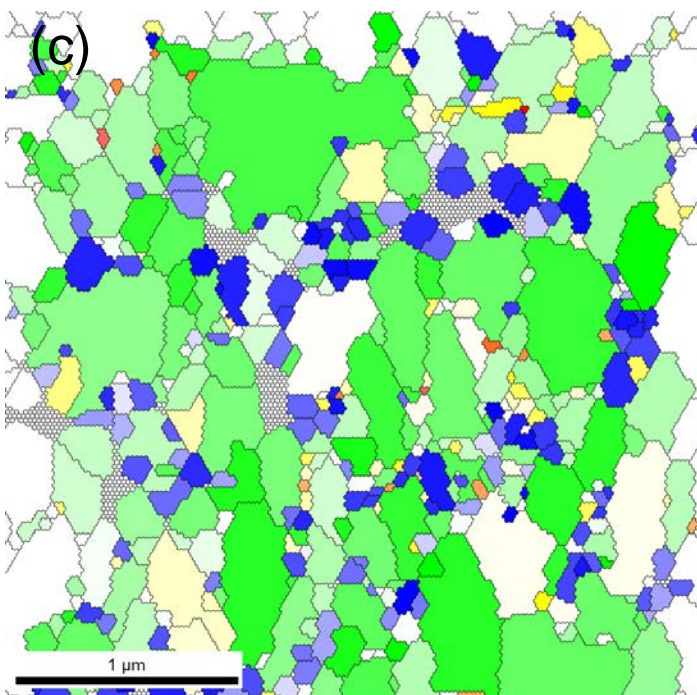
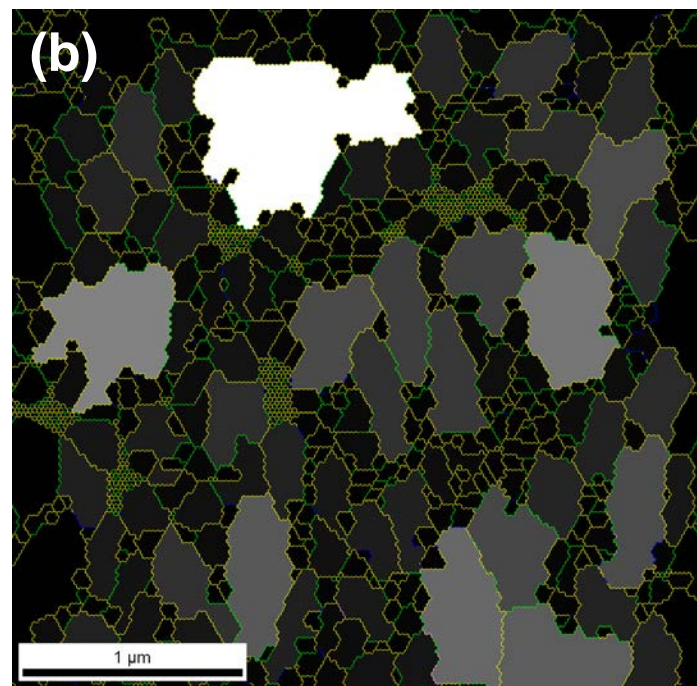
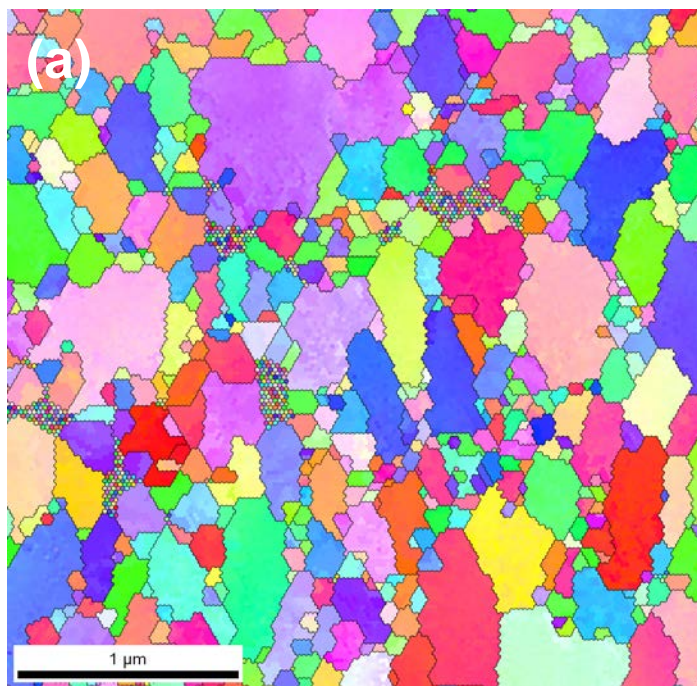
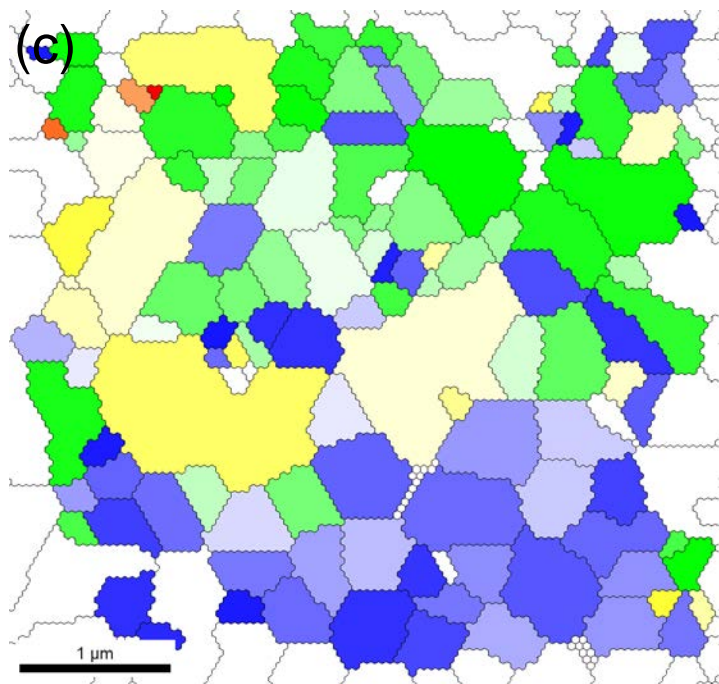
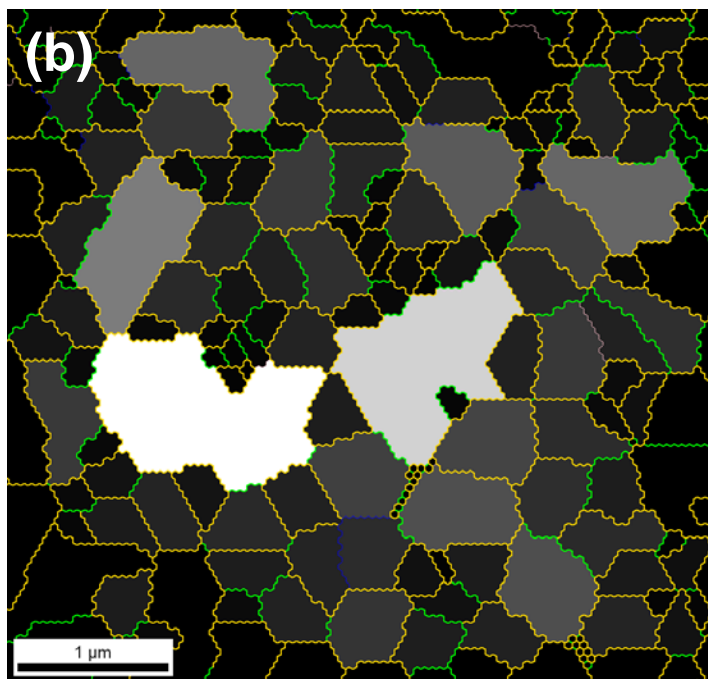
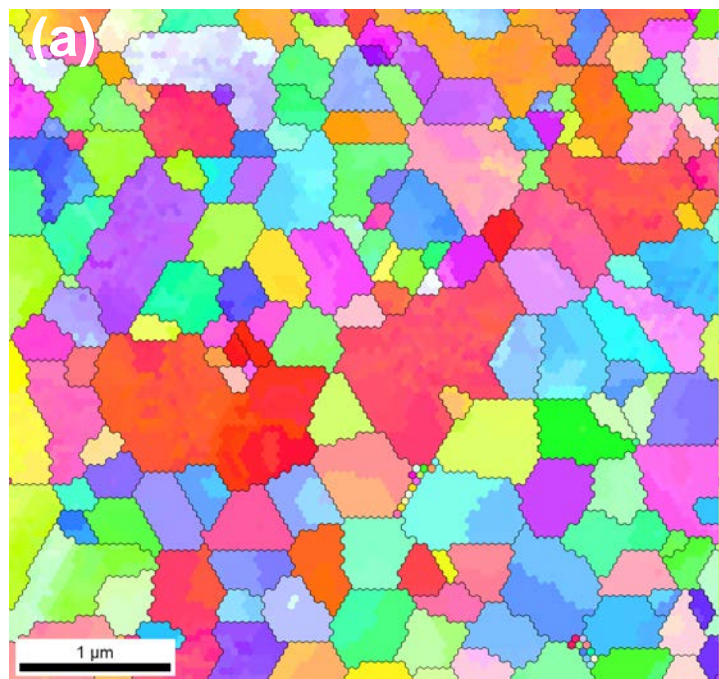


Fig. 5



- 5 – 10°
- 10 – 45°
- 45 – 90°
- 90 – 180°

- 0 – 0.62
- 0.62 – 1.15
- 1.15 – 1.75
- 1.75 – 1.95
- 1.95 – 2.44

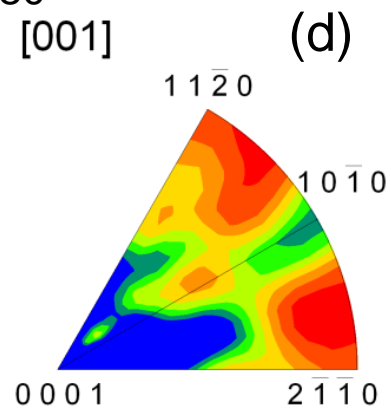


Fig. 6

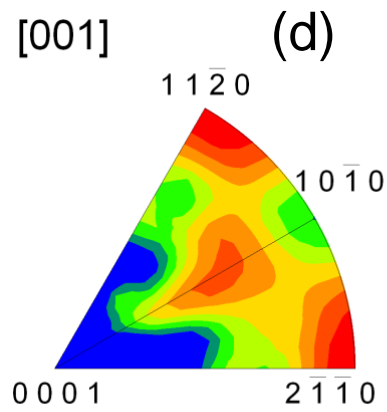
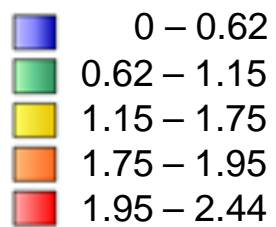
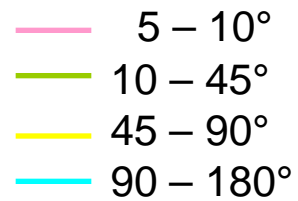
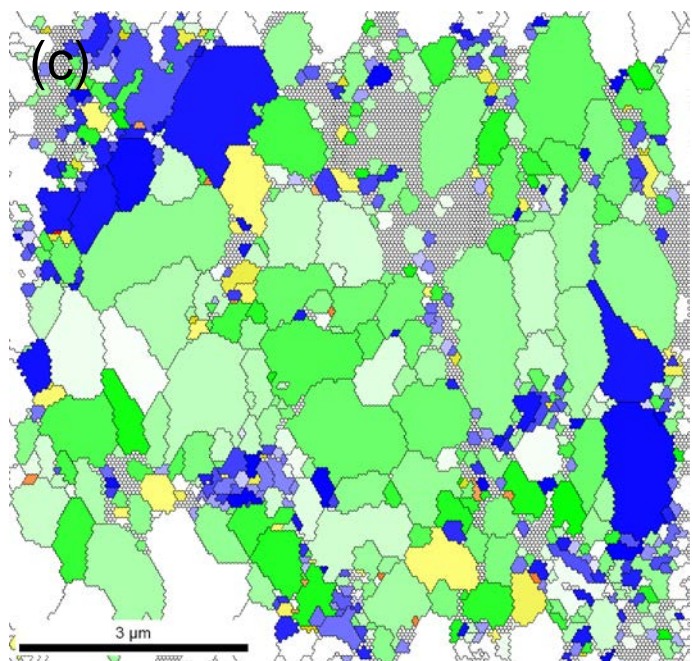
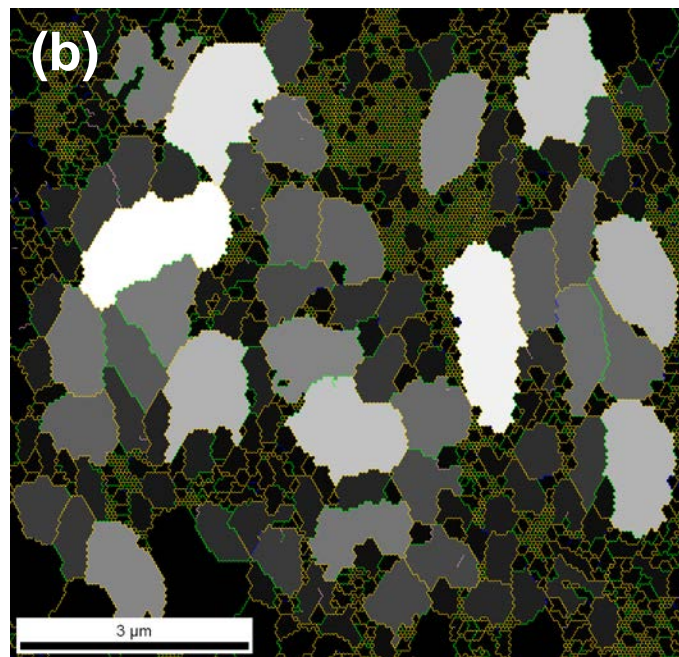
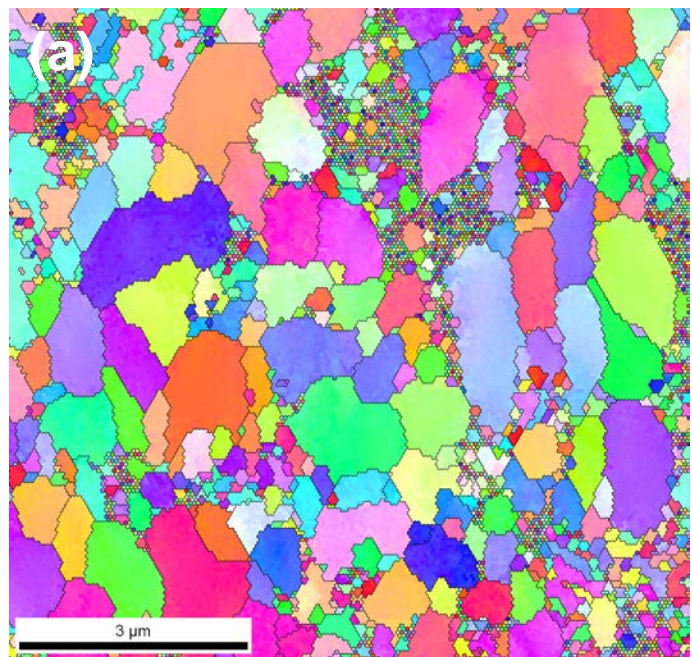


Fig. 7



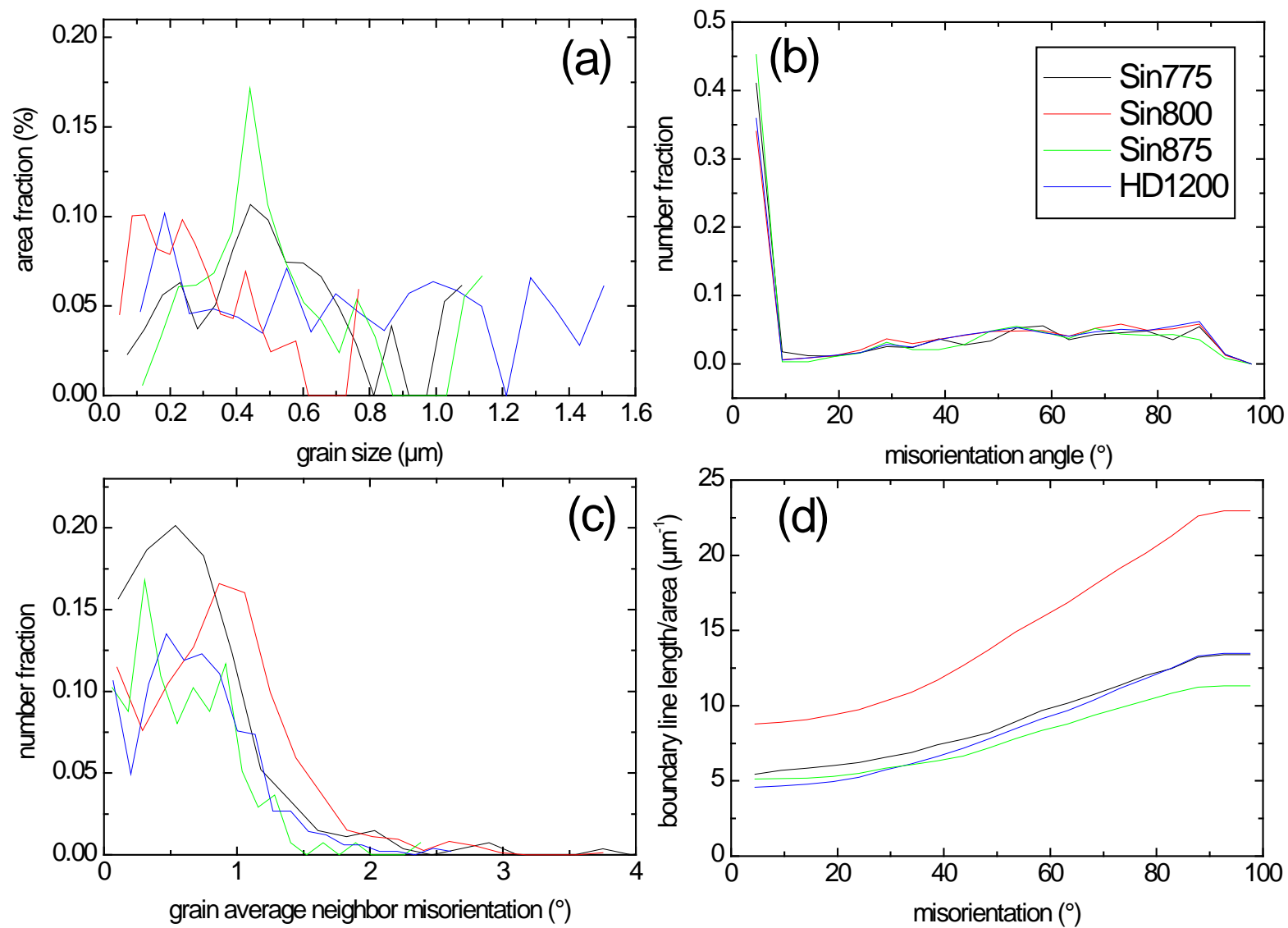


Fig. 8

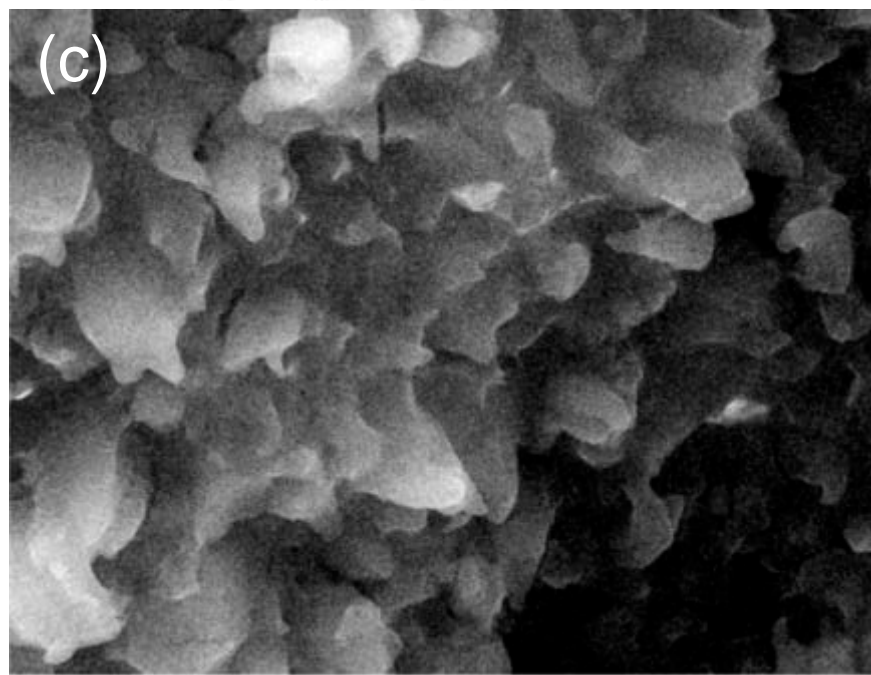
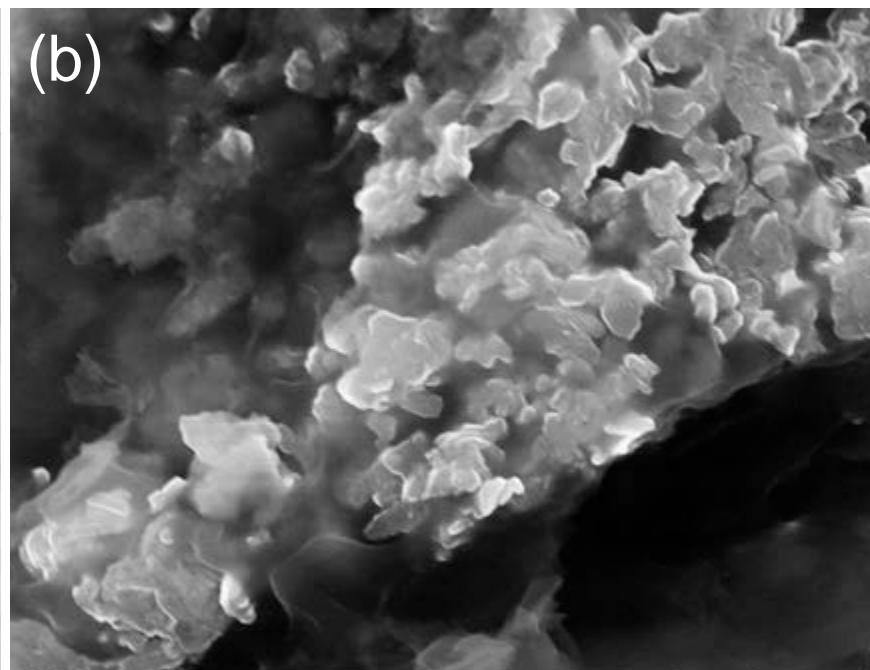
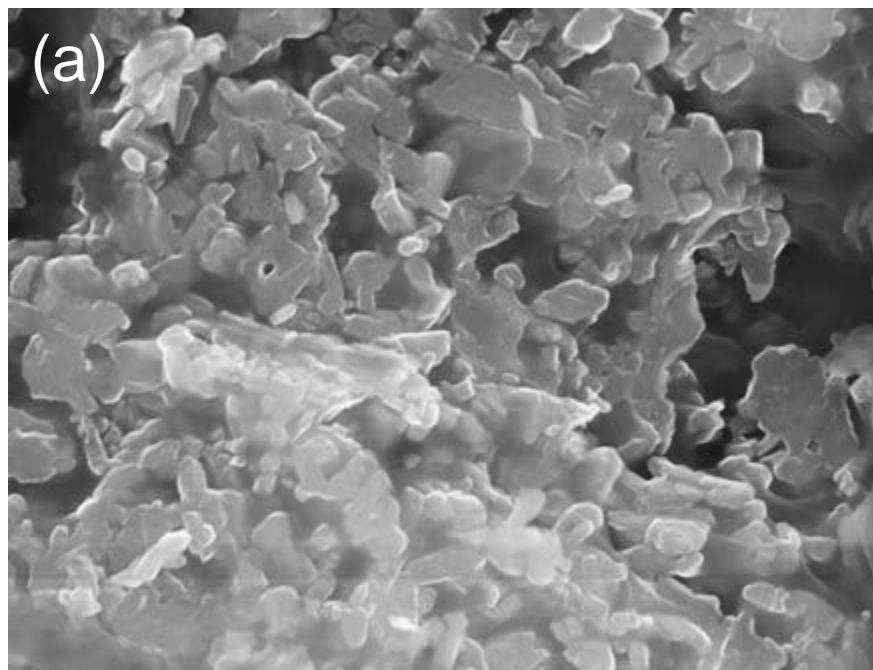


Fig. 9